

# Rectifier Diodes, Fast Recovery

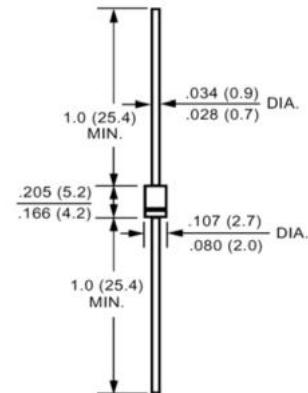


## FEATURES:

Fast switching for high efficiency  
High surge current capability

## SPECIFICATION:

Case	Molded plastic, DO-41
Epoxy	UL 94V-0 rate flame retardant
Lead	Axial leads
Polarity	Colour band denotes cathode end
Mounting position	Any



Art. Nr.

RND 1N4934

## Maximum Ratings and Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half-wave, 60 Hz, resistive or inductive load, for capacitive load, derate current by 20%.

Parameter	Symbols	RND 1N4933	RND 1N4934	RND 1N4935	RND 1N4936	RND 1N4937	Units
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	V
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	280	420	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	V
Maximum Average Forward Rectified Current 0.375" (9.5 mm) Lead Length at T <sub>A</sub> = 50 °C	I <sub>F(AV)</sub>			1			A
Peak Forward Surge Current 8.3 ms Single Half Sine-Wave Superimposed on Rated Load (JEDEC Method)	I <sub>FSM</sub>			30			A
Maximum Forward Voltage at 1 A	V <sub>F</sub>			1.2			V
Maximum Reverse Current at T <sub>A</sub> = 25 °C Rated DC Blocking Voltage T <sub>A</sub> = 125 °C	I <sub>R</sub>			5	50		µA
Maximum Reverse Recovery Time <sup>1)</sup>	t <sub>rr</sub>			150			ns
Typical Thermal Resistance, Junction to Ambient <sup>2)</sup>	R <sub>θJA</sub>			55			°C/W
Typical Thermal Resistance, Junction to Lead <sup>2)</sup>	R <sub>θJL</sub>			25			°C/W
Operating Junction temperature range	T <sub>j</sub>			- 55 to + 125			°C
Storage Temperature range	T <sub>stg</sub>			- 55 to + 150			°C

<sup>1)</sup> Reverse recovery test conditions: I<sub>F</sub> = 0.5 A, I<sub>R</sub> = 1 A, I<sub>rr</sub> = 0.25 A.

<sup>2)</sup> Thermal resistance from junction to ambient 0.375"(9.5 mm) lead length P.C.B mounted.

# Rectifier Diodes, Standard

## Standard Rectifier Diodes, Axial Lead

